NSN 5962-01-445-6150

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Body Length:
1.700 inches
Body Width:
Between 0.350 inches and 0.405 inches
Body Height:
0.232 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15i
Features Provided:
Burn in, mil-std-883, class b and electrostatic sensitive and hermetically sealed and monolithic and tested to mil-std-883 and low power ar
static operation
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
25 input
Criticality Code Justification:
Cbbl
Current Rating Per Characteristic:
135.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 5.5 volts input and -0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
12.00 input picofarads and 14.00 output picofarads
Time Rating Per Chacteristic:
35.00 nanoseconds access

Test Data Document:

Ram

Memory Device Type:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:
32 printed circuit
Specification Data:
67268-5962-89598 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

Fiig: A458a0